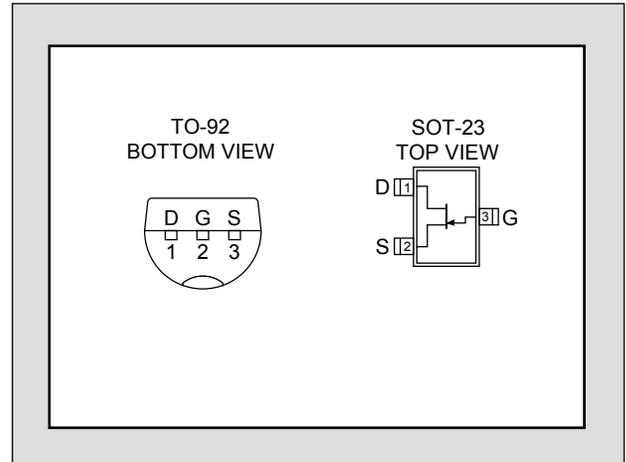


LSJ74

ULTRA LOW NOISE SINGLE P-CHANNEL JFET

FEATURES	
ULTRA LOW NOISE ($f = 1\text{kHz}$)	$e_n = 0.9\text{nV}/\sqrt{\text{Hz}}$
HIGH GAIN	$Y_{fs} = 22\text{mS (typ)}$
HIGH INPUT IMPEDANCE	$I_G = -1.0\text{nA}$
LOW CAPACITANCE	$C_{RSS} = 32\text{pF}$
IMPROVED SECOND SOURCE REPLACEMENT FOR 2SJ74	
ABSOLUTE MAXIMUM RATINGS ¹	
@ 25 °C (unless otherwise stated)	
Maximum Temperatures	
Storage Temperature	-65 to 150°C
Junction Operating Temperature	-55 to 135°C
Maximum Power Dissipation	
Continuous Power Dissipation	400mW
Maximum Currents	
Gate Forward Current	$I_{G(F)} = -10\text{mA}$
Maximum Voltages	
Gate to Drain Voltage	$V_{GDS} = 25\text{V}$
Gate to Source Voltage	$V_{GSS} = 25\text{V}$

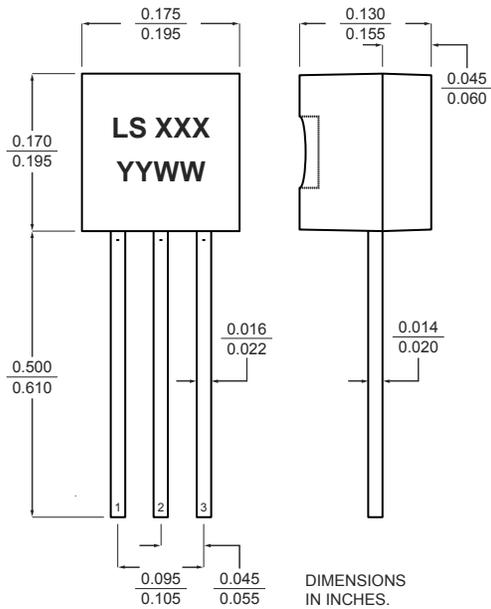


*For equivalent N-Channel, see LSK170 family.

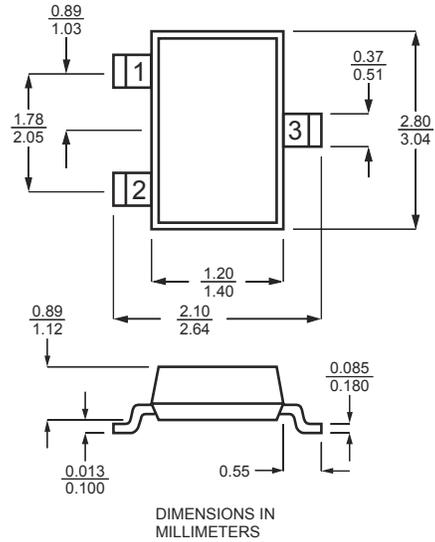
ELECTRICAL CHARACTERISTICS @ 25 °C (unless otherwise stated)

SYMBOL	CHARACTERISTIC	MIN	TYP	MAX	UNITS	CONDITIONS
BV_{GDS}	Gate to Drain Breakdown Voltage	25			V	$V_{DS} = 0\text{V}, I_G = 100\mu\text{A}$
$V_{GS(OFF)}$	Gate to Source Pinch Off Voltage	0.15		2		$V_{DS} = -10\text{V}, I_D = -0.1\mu\text{A}$
I_{DSS}	Drain to Source Saturation Current	LSJ74A	2.6	6.5	mA	$V_{DG} = -10\text{V}, V_{GS} = 0\text{V}$
		LSJ74B	6	12		
		LSJ74C	10	20		
		LSJ74D	20	30		
I_G	Gate Operating Current			-10	nA	$V_{DG} = -10\text{V}, I_D = -1\text{mA}$
I_{GSS}	Gate to Source Leakage Current			1	nA	$V_{GS} = 25\text{V}, V_{DS} = 0\text{V}$
Y_{fs}	Full Conduction Transconductance	8	22		mS	$V_{DG} = -10\text{V}, V_{GS} = 0\text{V}, f = 1\text{kHz}$
e_n	Noise Voltage		0.9	1.9	nV/ $\sqrt{\text{Hz}}$	$V_{DS} = -10\text{V}, I_D = -2\text{mA}, f = 1\text{kHz}, \text{NBW} = 1\text{Hz}$
			2.5	4		$V_{DS} = -10\text{V}, I_D = -2\text{mA}, f = 10\text{Hz}, \text{NBW} = 1\text{Hz}$
C_{ISS}	Common Source Input Capacitance		105		pF	$V_{DS} = -10\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$
C_{RSS}	Common Source Reverse Transfer Cap.		32			$V_{DG} = -10\text{V}, I_D = 0\text{A}, f = 1\text{MHz}$

TO-92



SOT-23



1. Absolute maximum ratings are limiting values above which serviceability may be impaired.

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